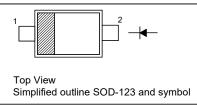
# Silicon Epitaxial Planar Switching Diode

#### **PINNING**

PIN	DESCRIPTION		
1	Cathode		
2	Anode		



## Absolute Maximum Ratings ( $T_a = 25$ °C)

Parameter		Symbol	Value	Unit
Repetitive Reverse Voltage		$V_{RRM}$	100	V
Average Rectified Forward Current		I <sub>F(AV)</sub>	215	mA
Non-repetitive Peak Forward Surge Current	at t = 1 s at t = 1 µs	I <sub>FSM</sub>	1 2	А
Power Dissipation		$P_D$	400	mW
Junction Temperature		T <sub>j</sub>	150	°C
Storage Temperature Range		$T_{stg}$	- 55 to + 150	Ô

#### **Thermal Characteristics**

Parameter	Symbol	Max.	Unit	
Thermal Resistance from Junction to Ambient 1)	$R_{ heta JA}$	313	°C/W	

<sup>1)</sup> Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



## 1N914W

## Electrical Characteristics (T<sub>a</sub> = 25°C)

Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage at $I_R = 5 \mu A$ at $I_R = 100 \mu A$	V <sub>(BR)R</sub>	75 100		V
Forward Voltage at I <sub>F</sub> = 10 mA	V <sub>F</sub>	-	1	V
Reverse Current at $V_R = 20 \text{ V}$ at $V_R = 75 \text{ V}$ at $V_R = 20 \text{ V}$ , $V_j = 150 ^{\circ}\text{C}$	I <sub>R</sub>		25 5 50	nΑ μΑ μΑ
Capacitance at $V_R = 0 \text{ V}$ , $f = 1 \text{ MHz}$	C <sub>tot</sub>	-	4	pF
Reverse Recovery Time at $I_F = 10 \text{ mA}$ , $V_R = 6 \text{ V}$ , $I_{rr} = 0.1 \text{ X}$ $I_R$ , $R_L = 100 \Omega$	t <sub>rr</sub>	-	4	ns



100

0

0

25

#### **Electrical Characteristics Curves**

Fig 1. Power Derating Curve 500 P<sub>tot</sub>, Power Dissipation (mW) 400 300 200

Fig 2. Capacitance Characteristics

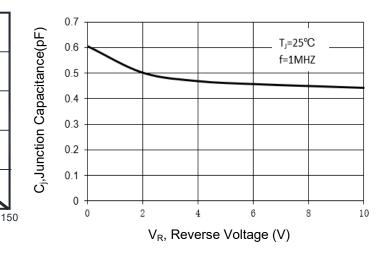


Fig 3. Reverse Characteristics

75

Ta, Ambient Temperature ( C)

100

125

50

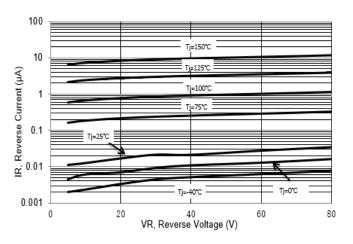
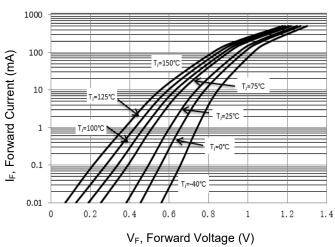


Fig 4. Forward Characteristics

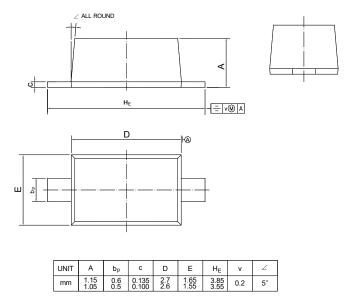




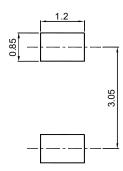
#### **PACKAGE OUTLINE**

### Plastic surface mounted package; 2 leads

**SOD-123** 



#### **Recommended Soldering Footprint**



**Packing information** 

Package	Tape Width	Pit	tch	Reel Size		Per Reel Packing Quantity
Fackage	(mm)	mm	(inch)	mm	(inch)	rei Neel Fackling Qualitity
SOD-123	8	4 ± 0.1	0.157 ± 0.004	178	7	3,000

#### **Marking information**

" W1 " = Part No.

" III " = Cathode line

Font type: Arial



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